

This IC is used for secondary protection of lithium-ion rechargeable batteries, and incorporates high-accuracy voltage detection circuits and delay circuits. The S-82M3A Series enable connection of 3-serial cell, and the S-82M4A Series enable connection of 4-serial cell.

This IC provides a wake-up function to prevent the fuse from blowing during battery connection, and allows the lithium battery to be connected in any order.

Since this IC also comes with a constant voltage output circuit capable of outputting 1.5 V to 3.3 V, it can be used as a constant-voltage power supply for an external RTC (Real-Time clock IC).

## ■ Features

- High-accuracy voltage detection circuit for each cell
 

Overcharge detection voltage n	3.600 V to 5.000 V (5 mV step)	Accuracy $\pm 15$ mV ( $T_a = +25^\circ\text{C}$ )
		Accuracy $\pm 20$ mV ( $T_a = -10^\circ\text{C}$ to $+60^\circ\text{C}$ )
Overcharge release voltage n*1	3.600 V to 5.000 V	Accuracy $\pm 50$ mV
VRTC pin shutdown voltage n	2.500 V to 2.800 V (100 mV step)	Accuracy $\pm 50$ mV
- The wake-up function monitoring battery connection prevents CO pin output errors during battery connection
- Delay times are generated only by an internal circuit (external capacitors are unnecessary)
 

Overcharge detection delay time, VRTC pin shutdown delay time:	1 s, 2 s, 4 s, 6 s
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- Output control function via CTL pin (CTL pin is pulled down internally)
- Overcharge timer reset function: Available, unavailable
- CO pin output voltage is limited to 7.5 V max.
- VRTC pin output voltage: 1.500 V to 3.300 V (100 mV step) Accuracy  $\pm 2\%$  ( $T_a = +25^\circ\text{C}$ )
- VRTC pin output current: 2 mA max.
- Wide operation temperature range:  $T_a = -40^\circ\text{C}$  to  $+85^\circ\text{C}$
- Low current consumption
 

During operation ( $V_{\text{CU}} - 1.0$ V for each cell):	4.0 $\mu\text{A}$ max.
During VRTC pin shutdown ( $V_{\text{RSD}} - 1.0$ V for each cell):	1.0 $\mu\text{A}$ max.
- Lead-free (Sn 100%), halogen-free

\*1. Overcharge release voltage = Overcharge detection voltage – Overcharge hysteresis voltage  
(Overcharge hysteresis voltage can be selected from a range of 0 mV to 400 mV in 50 mV step.)

**Remark** n = 1, 2, 3, 4

## ■ Application

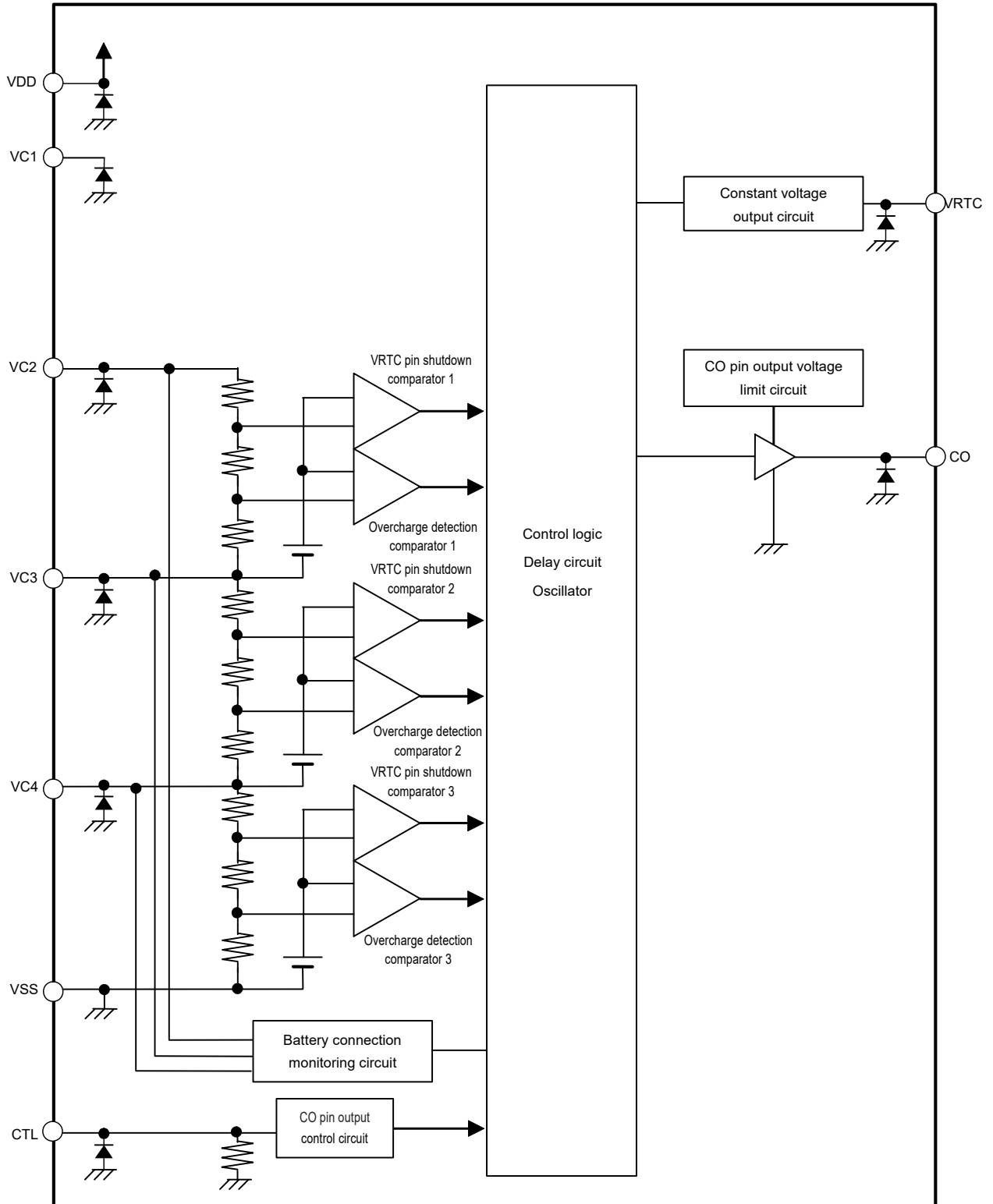
- Lithium-ion rechargeable battery packs (for secondary protection)

## ■ Package

- DFN-8(2020)A

■ **Block Diagrams**

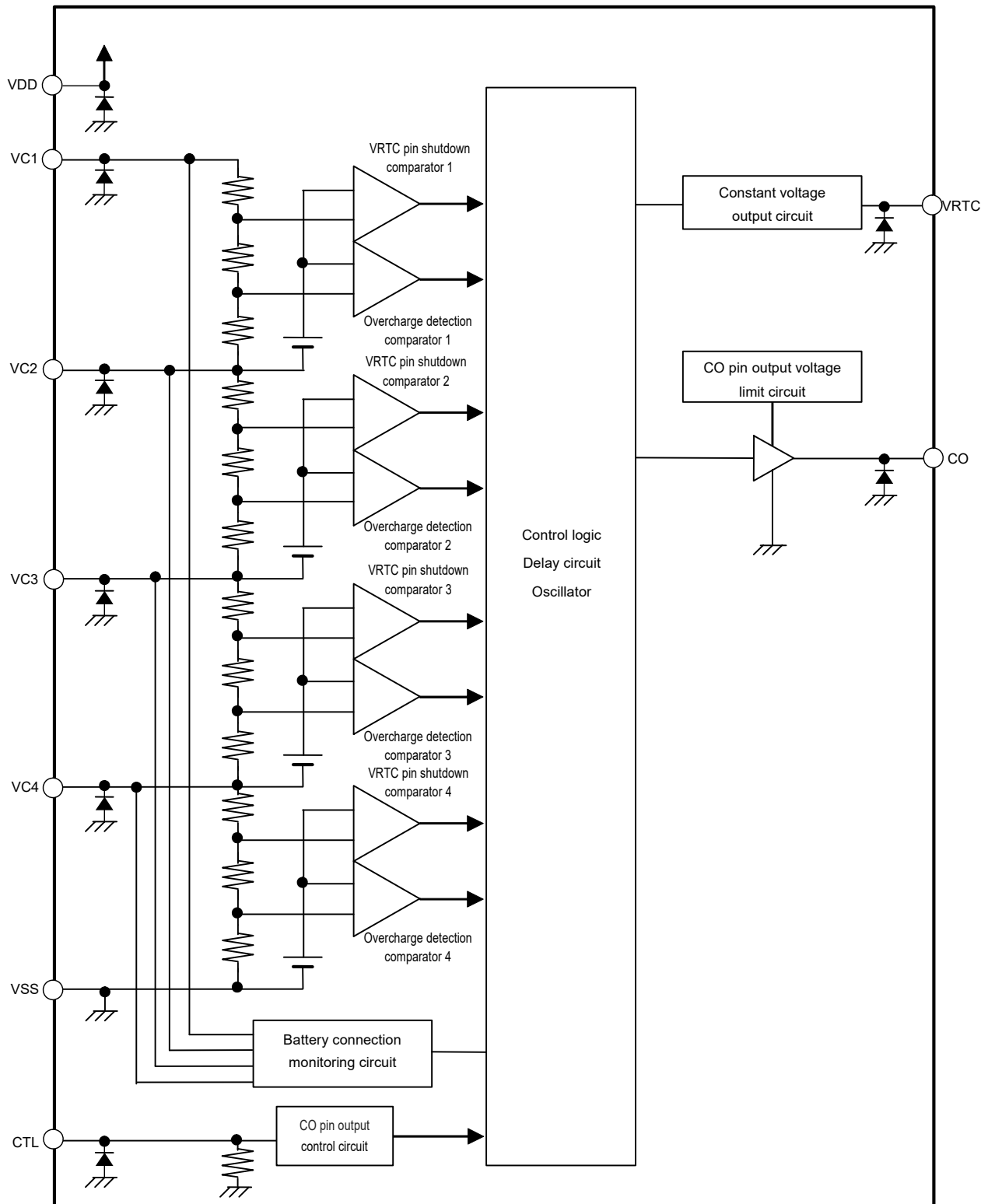
1. **S-82M3A Series**



**Remark** Diodes in the figure are parasitic diodes.

**Figure 1**

2. S-82M4A Series

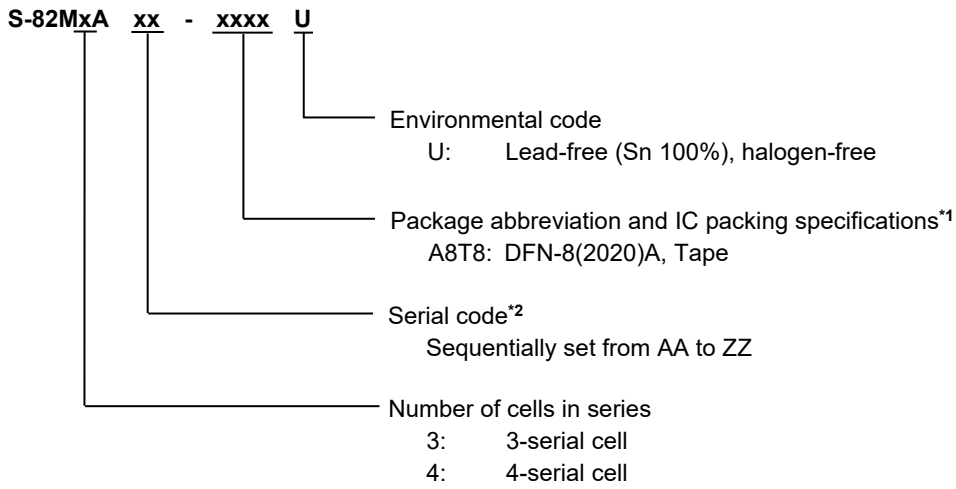


**Remark** Diodes in the figure are parasitic diodes.

Figure 2

■ **Product Name Structure**

**1. Product name**



\*1. Refer to the tape drawing.

\*2. Refer to "3. Product name list".

**2. Package**

**Table 1 Package Drawing Codes**

Package Name	Dimension	Tape	Reel	Land
DFN-8(2020)A	IB008-A-P-SD	IB008-A-C-SD	IB008-A-R-SD	IB008-A-L-SD

### 3. Product name list

#### 3.1 S-82M3A Series

Table 2

Product Name	Overcharge Detection Voltage [V <sub>CU</sub> ]	Overcharge Release Voltage [V <sub>CL</sub> ]	VRTC Pin Output Voltage [V <sub>VRTC</sub> ]	VRTC Pin Shutdown Voltage [V <sub>RSD</sub> ]	VRTC Pin Recovery Voltage [V <sub>RST</sub> ]	Overcharge Detection Delay Time* <sup>1</sup> [t <sub>CU</sub> ]	VRTC Pin Shutdown Delay Time* <sup>1</sup> [t <sub>RSD</sub> ]	Overcharge Timer Reset Function* <sup>2</sup>
S-82M3AAA-A8T8U	4.600 V	4.200 V	1.500 V	2.500 V	2.700 V	6 s	6 s	Unavailable

\*1. Overcharge detection delay time, VRTC pin shutdown delay time: 1 s, 2 s, 4 s, 6 s

\*2. Overcharge timer reset function: Available, unavailable

**Remark** Please contact our sales representatives for products other than the above.

#### 3.2 S-82M4A Series

Table 3

Product Name	Overcharge Detection Voltage [V <sub>CU</sub> ]	Overcharge Release Voltage [V <sub>CL</sub> ]	VRTC Pin Output Voltage [V <sub>VRTC</sub> ]	VRTC Pin Shutdown Voltage [V <sub>RSD</sub> ]	VRTC Pin Recovery Voltage [V <sub>RST</sub> ]	Overcharge Detection Delay Time* <sup>1</sup> [t <sub>CU</sub> ]	VRTC Pin Shutdown Delay Time* <sup>1</sup> [t <sub>RSD</sub> ]	Overcharge Timer Reset Function* <sup>2</sup>
S-82M4AAA-A8T8U	4.600 V	4.200 V	1.500 V	2.500 V	2.700 V	6 s	6 s	Unavailable

\*1. Overcharge detection delay time, VRTC pin shutdown delay time: 1 s, 2 s, 4 s, 6 s

\*2. Overcharge timer reset function: Available, unavailable

**Remark** Please contact our sales representatives for products other than the above.

■ Pin Configuration

1. DFN-8(2020)A

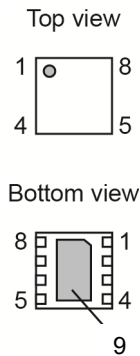


Figure 3

Table 4 S-82M3A Series

Pin No.	Symbol	Description
1	VDD	Positive power supply input pin
2	VC1	Positive power supply input pin
3	VC2	Positive voltage connection pin of battery 1
4	VC3	Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2
5	VC4	Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3
6	VRTC	Voltage output pin for Real-time Clock (RTC)
7	CTL	CO pin output control pin
8	CO	FET gate connection pin for charge control
9	VSS	Negative power supply input pin, Negative voltage connection pin of battery 3

Table 5 S-82M4A Series

Pin No.	Symbol	Description
1	VDD	Positive power supply input pin
2	VC1	Positive power supply input pin, Positive voltage connection pin of battery 1
3	VC2	Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2
4	VC3	Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3
5	VC4	Negative voltage connection pin of battery 3, Positive voltage connection pin of battery 4
6	VRTC	Voltage output pin for Real-time Clock (RTC)
7	CTL	CO pin output control pin
8	CO	FET gate connection pin for charge control
9	VSS	Negative power supply input pin, Negative voltage connection pin of battery 4

## ■ Absolute Maximum Ratings

Table 6

(Ta = +25°C unless otherwise specified)

Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	V <sub>DS</sub>	VDD	V <sub>SS</sub> – 0.3 to V <sub>SS</sub> + 28	V
Input voltage between VC1 pin and VSS pin	V <sub>VC1</sub>	VC1	V <sub>SS</sub> – 0.3 to V <sub>SS</sub> + 28	V
Input pin voltage	V <sub>IN</sub>	VC2, VC3, VC4, CTL	V <sub>SS</sub> – 0.3 to V <sub>VC1</sub> + 0.3	V
CO pin output voltage	V <sub>CO</sub>	CO	V <sub>SS</sub> – 0.3 to V <sub>SS</sub> + 8	V
VRTC pin output voltage	V <sub>VRTC</sub>	VRTC	V <sub>SS</sub> – 0.3 to V <sub>SS</sub> + 6	V
Operation ambient temperature	T <sub>opr</sub>	–	–40 to +85	°C
Storage temperature	T <sub>stg</sub>	–	–40 to +125	°C

**Caution** The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

## ■ Thermal Resistance Value

Table 7

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
Junction-to-ambient thermal resistance*1	$\theta_{JA}$	DFN-8(2020)A	Board A	–	242	–	°C/W
			Board B	–	182	–	°C/W
			Board C	–	–	–	°C/W
			Board D	–	–	–	°C/W
			Board E	–	–	–	°C/W

\*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

**Remark** Refer to "■ Power Dissipation" and "Test Board" for details.

■ **Electrical Characteristics**

**Table 8**

(Ta = +25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
<b>Detection Voltage</b>							
Overcharge detection voltage n (n = 1, 2, 3, 4)	V <sub>CU<sub>n</sub></sub>	Ta = +25°C	V <sub>CU</sub> - 0.015	V <sub>CU</sub>	V <sub>CU</sub> + 0.015	V	1
		Ta = -10°C to +60°C*1	V <sub>CU</sub> - 0.020	V <sub>CU</sub>	V <sub>CU</sub> + 0.020	V	1
Overcharge release voltage n (n = 1, 2, 3, 4)	V <sub>CL<sub>n</sub></sub>	-	V <sub>CL</sub> - 0.050	V <sub>CL</sub>	V <sub>CL</sub> + 0.050	V	1
VRTC pin shutdown voltage n (n = 1, 2, 3, 4)	V <sub>RSD<sub>n</sub></sub>	-	V <sub>RSD</sub> - 0.050	V <sub>RSD</sub>	V <sub>RSD</sub> + 0.050	V	2
VRTC pin recovery voltage n (n = 1, 2, 3, 4)	V <sub>RST<sub>n</sub></sub>	-	V <sub>RST</sub> - 0.100	V <sub>RST</sub>	V <sub>RST</sub> + 0.100	V	2
<b>Input Voltage</b>							
Operation voltage between VDD pin and VSS pin	V <sub>DSOP</sub>	-	3.6	-	24	V	-
CTL pin reverse voltage	V <sub>CTL</sub>	-	V <sub>DD</sub> × 0.4	-	V <sub>DD</sub> × 0.95	V	2
<b>Output Voltage</b>							
CO pin output voltage "H"	V <sub>COH</sub>	-	4.0	6.0	7.5	V	2
<b>Input Current</b>							
Current consumption during operation	I <sub>OPE</sub>	V1 = V2 = V3 = V4 = V <sub>CU</sub> - 1.0 V	-	2.0	4.0	μA	2
Current consumption during VRTC pin shutdown	I <sub>OPED</sub>	V1 = V2 = V3 = V4 = V <sub>RSD</sub> - 1.0 V	-	-	1.0	μA	2
VC1 pin input current	I <sub>VC1</sub>	V1 = V2 = V3 = V4 = V <sub>CU</sub> - 1.0 V	-	-	3.7	μA	2
VC <sub>n</sub> pin input current (n = 2, 3, 4)	I <sub>VC<sub>n</sub></sub>	V1 = V2 = V3 = V4 = V <sub>CU</sub> - 1.0 V	-0.42	0	-	μA	2
CTL pin input current "H"	I <sub>CTLH</sub>	V1 = V2 = V3 = V4 = 3.5 V, V <sub>CTL</sub> = V <sub>VC1</sub>	0.6	1.3	2.2	μA	2
CTL pin input current "L"	I <sub>CTLL</sub>	V1 = V2 = V3 = V4 = 3.5 V, V <sub>CTL</sub> = 0 V	-0.15	-	-	μA	2
<b>Output Current</b>							
CO pin source current	I <sub>COH</sub>	-	-	-	-20	μA	2
CO pin sink current	I <sub>COL</sub>	-	300	-	-	μA	2
<b>Delay Time</b>							
Overcharge detection delay time	t <sub>CU</sub>	-	t <sub>CU</sub> × 0.7	t <sub>CU</sub>	t <sub>CU</sub> × 1.3	s	2
Overcharge release delay time	t <sub>CL</sub>	-	8	16	32	ms	2
Overcharge timer reset delay time	t <sub>TR</sub>	With overcharge timer reset function	6	12	20	ms	-
CTL pin response delay time	t <sub>CTL</sub>	-	-	-	2.6	ms	2
Transition time to test mode	t <sub>TST</sub>	-	-	-	10	ms	-
VRTC pin shutdown delay time	t <sub>RSD</sub>	-	t <sub>RSD</sub> × 0.7	t <sub>RSD</sub>	t <sub>RSD</sub> × 1.3	s	2
Wake-up delay time	t <sub>WU</sub>	-	1	2	3	s	2
<b>VRTC Pin Output</b>							
VRTC pin output voltage	V <sub>VRTC</sub>	I <sub>VRTC</sub> = 10 μA, SW2 = ON, V1 = V2 = V3 = V4 = 3.5 V	V <sub>VRTC</sub> × 0.98	V <sub>VRTC</sub>	V <sub>VRTC</sub> × 1.02	V	2
VRTC pin output current	I <sub>VRTC</sub>	-	-	-	2	mA	-

\*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.



■ Test Circuit

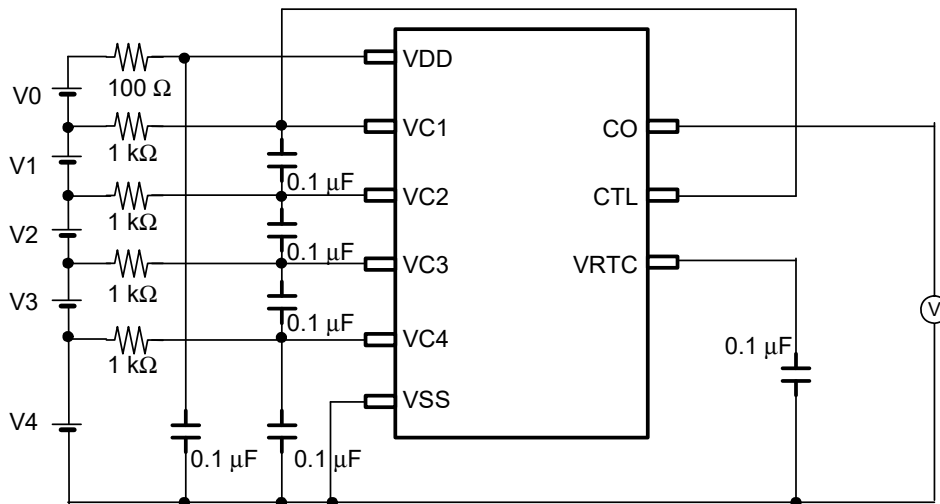


Figure 4 Test Circuit 1

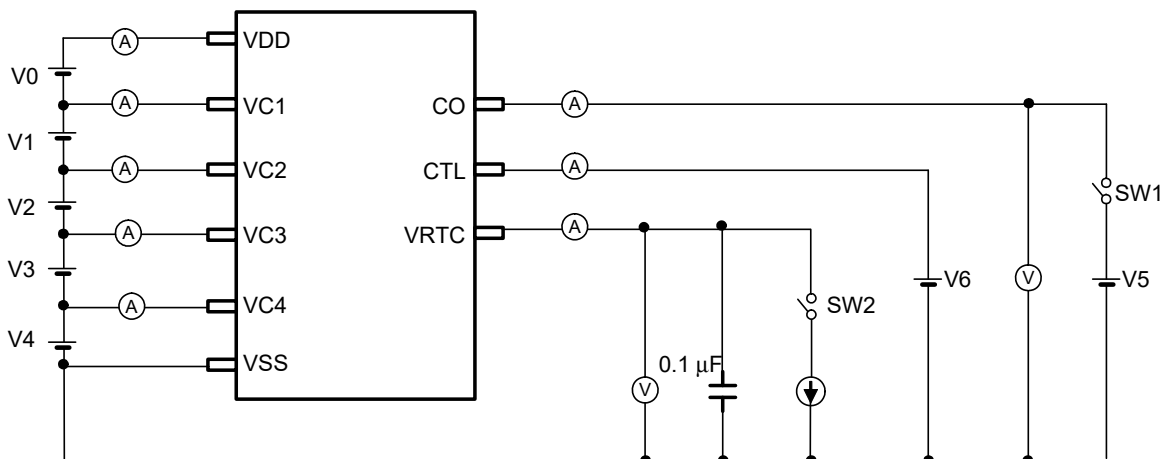


Figure 5 Test Circuit 2

In the initial status of the test circuit, SW1 and SW2 should be OFF and  $V6 = V1 + V2 + V3 + V4$ . This section provides explanations of test items using test circuit 1 and test circuit 2.

**1. Overcharge detection voltage n ( $V_{CU_n}$ ), overcharge release voltage n ( $V_{CL_n}$ ) (Test Circuit 1)**

After setting  $V0 = 0\text{ V}$  and  $V1 = V2 = V3 = V4 = V_{CU} - 0.1\text{ V}$ , V1 is gradually increased. When the CO pin becomes "H" ( $V_{COH}$ ), the voltage of V1 is defined as the overcharge detection voltage 1 ( $V_{CU1}$ ). After that, set  $V1 = V_{CU} + 0.1\text{ V}$  and  $V2 = V3 = V4 = 3.5\text{ V}$ , and then V1 is gradually decreased. When the CO pin becomes "L" ( $V_{SSL}$ ), the voltage of V1 is defined as the overcharge release voltage 1 ( $V_{CL1}$ ).

Overcharge detection voltage n ( $V_{CU_n}$ ) and overcharge release voltage n ( $V_{CL_n}$ ) can be determined in the same way as when  $n = 1$ .

**Remark**  $n = 1, 2, 3, 4$

## 2. VRTC pin shutdown voltage n ( $V_{RSDn}$ ), VRTC pin recovery voltage n ( $V_{RSTn}$ ) (Test Circuit 2)

After setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ ,  $V_1$  is gradually decreased. When the VRTC pin output becomes  $V_{SS}$ , the voltage of  $V_1$  is defined as the VRTC pin shutdown voltage 1 ( $V_{RSD1}$ ). After that, set  $V_1 = V_{RSD} - 0.15\text{ V}$  and  $V_2 = V_3 = V_4 = 3.5\text{ V}$ , and then  $V_1$  is gradually increased. When the VRTC pin output voltage becomes the VRTC pin output voltage ( $V_{VRTC}$ ), the voltage of  $V_1$  is defined as the VRTC pin recovery voltage 1 ( $V_{RST1}$ ).

VRTC pin shutdown voltage n ( $V_{RSDn}$ ) and VRTC pin recovery voltage n ( $V_{RSTn}$ ) can be determined in the same way as when  $n = 1$ .

## 3. CTL pin reverse voltage ( $V_{CTL}$ ) (Test Circuit 2)

After setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ ,  $V_6$  is gradually decreased. When the CO pin becomes "H," the voltage of  $V_6$  is defined as the CTL pin reverse voltage ( $V_{CTL}$ ).

## 4. CO pin output voltage "H" ( $V_{COH}$ ) (Test Circuit 2)

The CO pin output voltage "H" ( $V_{COH}$ ) is the voltage between the CO pin and the VSS pin when  $V_0 = 0\text{ V}$ ,  $V_1 = 5.1\text{ V}$ , and  $V_2 = V_3 = V_4 = 3.5\text{ V}$ .

## 5. Current consumption during operation ( $I_{OPE}$ ), current consumption during VRTC pin shutdown ( $I_{OPED}$ ) (Test Circuit 2)

The current consumption during operation ( $I_{OPE}$ ) is the total of the currents that flow in the VDD, VC1, VC2, VC3, and VC4 pins after setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = V_{CU} - 1.0\text{ V}$ . The current consumption during VRTC pin shutdown ( $I_{OPED}$ ) is the total of the currents that flow in the VDD, VC1, VC2, VC3, and VC4 pins after setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = V_{RSD} - 1.0\text{ V}$ .

## 6. CO pin source current ( $I_{COH}$ ) (Test Circuit 2)

Set SW1 to ON after setting  $V_0 = 0\text{ V}$ ,  $V_1 = 5.1\text{ V}$ ,  $V_2 = V_3 = V_4 = 3.5\text{ V}$ , and  $V_5 = V_{COH} - 0.5\text{ V}$ . The CO pin current is the CO pin source current ( $I_{COH}$ ) at that time.

## 7. CO pin sink current ( $I_{COL}$ ) (Test Circuit 2)

Set SW1 to ON after setting  $V_0 = 0\text{ V}$ ,  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ , and  $V_5 = 0.5\text{ V}$ . The CO pin current is the CO pin sink current ( $I_{COL}$ ) at that time.

## 8. Overcharge detection delay time ( $t_{CU}$ ), overcharge release delay time ( $t_{CL}$ ) (Test Circuit 2)

After setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ ,  $V_1$  is increased to  $5.1\text{ V}$ . The overcharge detection delay time ( $t_{CU}$ ) is the time period until the CO pin becomes "H". After that, decrease  $V_1$  to  $3.5\text{ V}$ . The overcharge release delay time ( $t_{CL}$ ) is the time period until the CO pin becomes "L".

## 9. VRTC pin shutdown delay time ( $t_{RSD}$ ) (Test Circuit 2)

After setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ ,  $V_1$  is decreased to  $2.4\text{ V}$ . The VRTC pin shutdown delay time ( $t_{RSD}$ ) is the time period until the VRTC pin output begins invert.

## 10. CTL pin response delay time ( $t_{CTL}$ ) (Test Circuit 2)

After setting  $V_0 = 0\text{ V}$  and  $V_1 = V_2 = V_3 = V_4 = 3.5\text{ V}$ ,  $V_6$  is instantly decreased to  $0\text{ V}$  from  $14\text{ V}$ . The CTL pin response delay time ( $t_{CTL}$ ) is the time period from when  $V_6$  turns  $0\text{ V}$  until the CO pin becomes "H".

**Remark**  $n = 1, 2, 3, 4$

## ■ Operation

**Remark** Refer to "■ Battery Protection IC Connection Examples".

### 1. Wake-up function operation during battery connection

The IC monitors whether or not all batteries have been connected to prevent CO pin output errors during battery connection from blowing the protection fuse. When all batteries have been connected, the IC transitions to the normal status. This is what we call the wake-up function. When 3.5 V or higher voltage batteries are connected to all battery connection pins and this state continues for at least the wake-up delay time ( $t_{WU}$ ) = 2.0 s typ., the VRTC pin outputs the VRTC pin output voltage ( $V_{VRTC}$ ) and the device enters the normal status.

No other operations are possible until the IC is in the normal status. The wake-up function is disabled when the IC enters the normal status and is enabled access to other operations.

### 2. Normal status

When all battery voltages are higher than the VRTC pin shutdown voltage  $n$  ( $V_{RSDn}$ ) but lower than overcharge detection voltage  $n$  ( $V_{CUn}$ ), the CO pin outputs "L" and the VRTC pin outputs  $V_{VRTC}$ . This status is called the normal status.

### 3. Overcharge status

When the voltage of any of all batteries exceeds the overcharge detection voltage  $n$  ( $V_{CUn}$ ) and this condition continues for the overcharge detection delay time ( $t_{CU}$ ) or longer, the CO pin outputs "H" ( $V_{COH}$ ). This status is called the overcharge status. Charge control and secondary protection can be enabled by connecting an FET to the CO pin.

When all battery voltages fall below the overcharge release voltage  $n$  ( $V_{CLn}$ ) and this condition continues for the overcharge release delay time ( $t_{CL}$ ) or longer, this IC returns to the normal status.

### 4. VRTC pin shutdown status

When the voltage of any of the batteries falls below the VRTC pin shutdown voltage  $n$  ( $V_{RSDn}$ ) and this condition continues for the VRTC pin shutdown delay time ( $t_{RSD}$ ) or longer, the VRTC pin output becomes  $V_{SS}$ . This status is called the VRTC pin shutdown status.

When all battery voltages exceed the VRTC pin recovery voltage  $n$  ( $V_{RSTn}$ ), this IC returns to the normal status.

### 5. Overcharge timer reset function

During  $t_{CU}$ , which is from when the voltage of any of the batteries being charged exceeds  $V_{CUn}$  until charging stops, this IC has the following operations.

Even if an overcharge release noise, which temporarily forces the battery voltage below  $V_{CUn}$ , is input,  $t_{CU}$  is continuously counted as long as the overcharge release noise time is shorter than the overcharge timer reset delay time ( $t_{TR}$ ). Under the same conditions, if the overcharge release noise time is  $t_{TR}$  or longer, counting of  $t_{CU}$  is reset once. After that, when  $V_{CUn}$  has been exceeded, counting of  $t_{CU}$  resumes.

**Remark**  $n = 1, 2, 3, 4$

**6. CTL pin**

The CTL pin is used to control the output voltage of the CO pin. The CTL pin takes precedence over the overcharge detection circuit.

The reverse voltage "H" to "L" or "L" to "H" of CTL pin is VC1 pin voltage – 2.8 V (typ.), does not have the hysteresis.

**Table 9 Control via CTL Pin**

CTL Pin	CO Pin
"H"	Normal status*1
Open	Detection status
"L"	Detection status

\*1. The status is controlled by the overcharge detection circuit.

**Caution** Since the CTL pin implements high resistance of 6 M $\Omega$  to 23 M $\Omega$  for pull down, be careful of external noise application. If an external noise is applied, the CO pin may become "H". Perform thorough evaluation using the actual application.

**Remark** n = 1, 2, 3, 4

**7. Test mode**

In this IC, the overcharge detection delay time ( $t_{cu}$ ) and VRTC pin shutdown delay time ( $t_{rSD}$ ) can be shortened by entering the test mode.

The test mode can be set by retaining the VDD pin voltage 7.0 V or higher than the VC1 pin voltage for at least 10 ms ( $V1 = V2 = V3 = V4 = 3.5\text{ V}$ ,  $T_a = +25^\circ\text{C}$ ). The status is retained by the internal latch and the test mode is retained even if the VDD pin voltage is decreased to the same voltage as that of the VC1 pin.

When this IC becomes the detection status after the delay time following the detection of an overcharge or VRTC pin shutdown has elapsed, the latch for retaining the test mode is reset and this IC is released from the test mode.

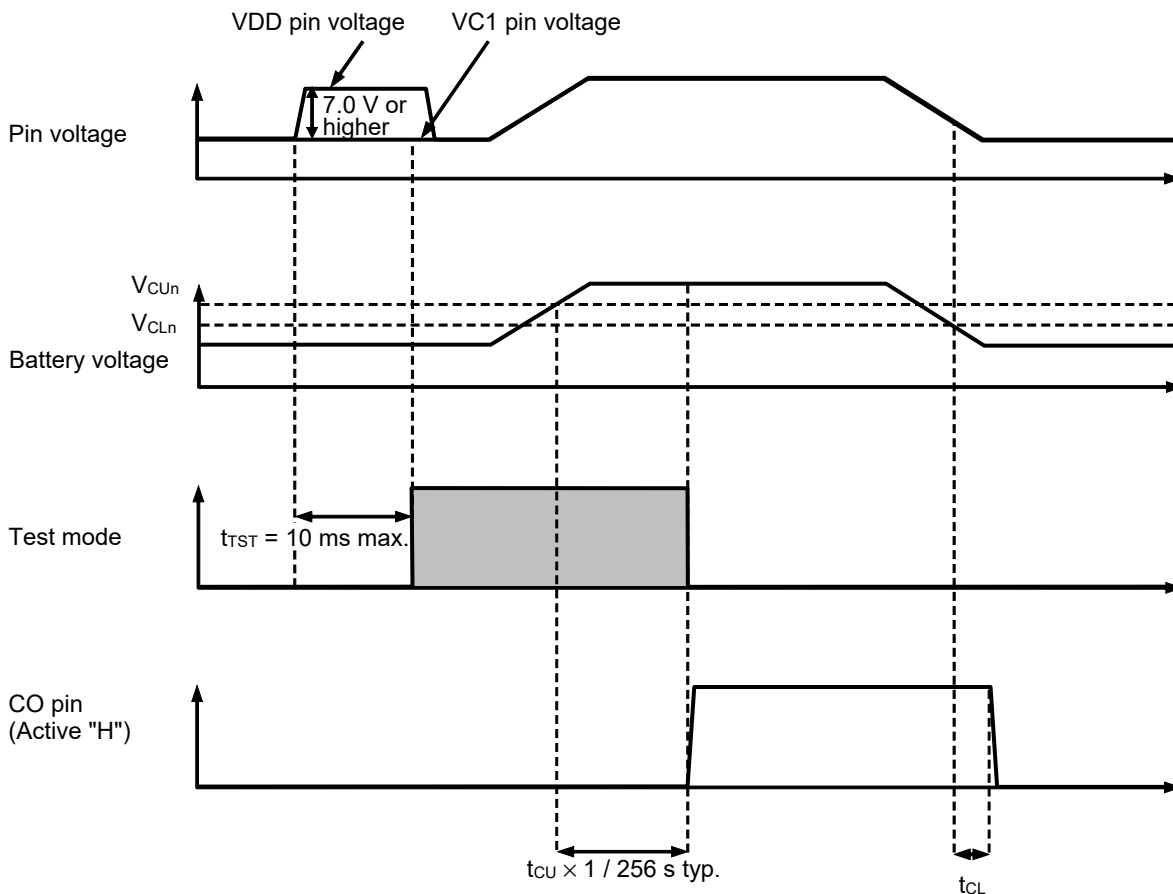


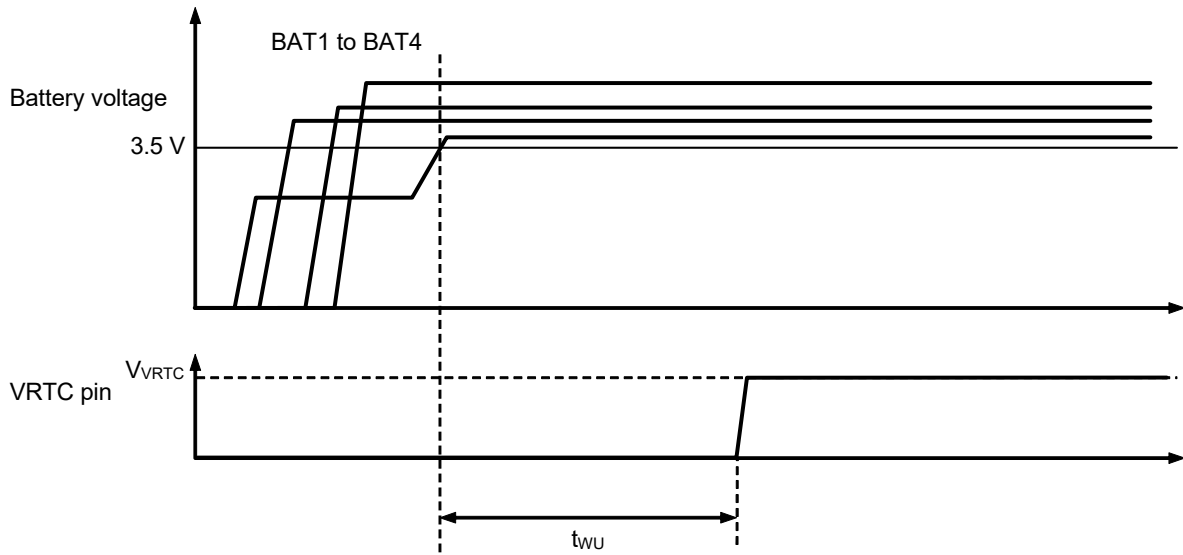
Figure 6

- Caution**
1. Set the test mode when no batteries are overcharged.
  2. The overcharge timer reset delay time ( $t_{TR}$ ) is not shortened in the test mode.

**Remark** n = 1, 2, 3, 4

■ **Timing Charts**

1. **Wake-up function operation during battery connection (S-82M4A Series)**



**Figure 7**

2. Overcharge detection operation (With overcharge timer reset function)

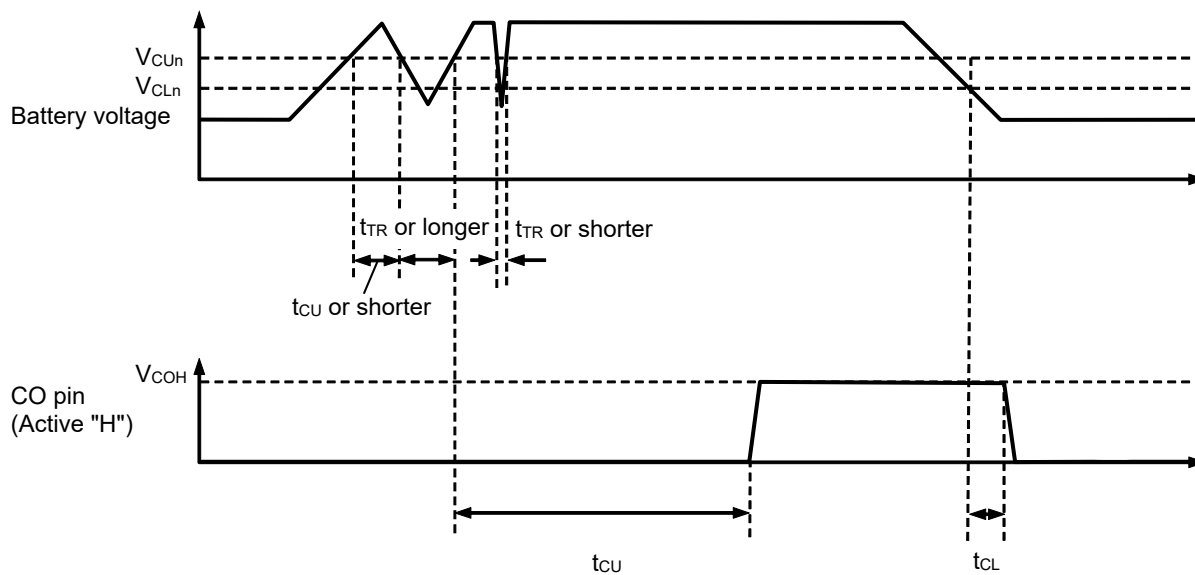
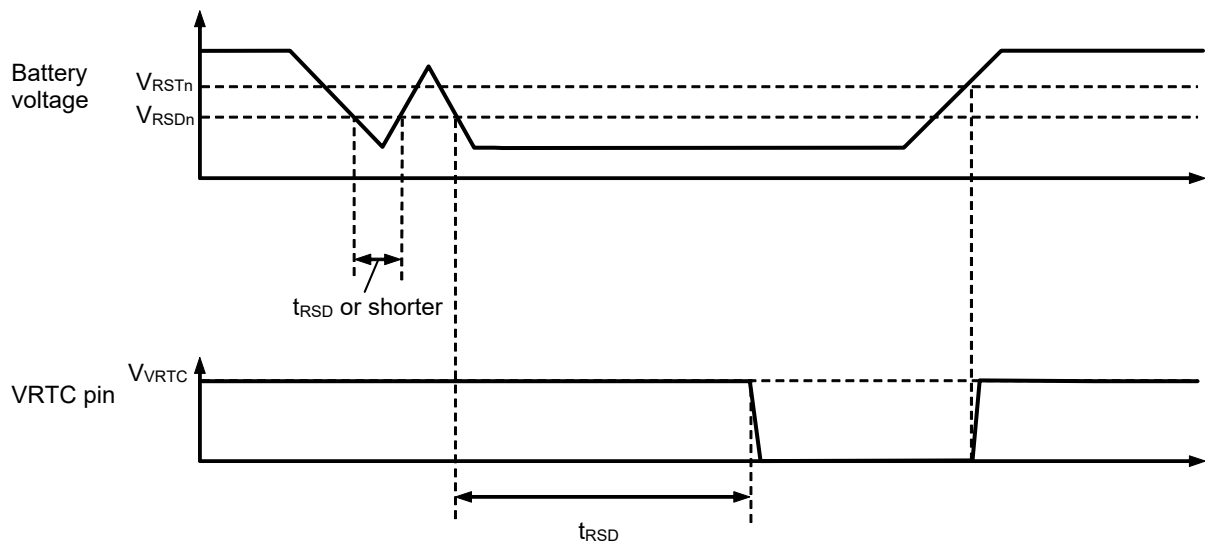


Figure 8

Remark n = 1, 2, 3, 4

**3. VRTC pin shutdown operation**



**Figure 9**

**Remark** n = 1, 2, 3, 4



4. Overcharge timer reset operation (With overcharge timer reset function)

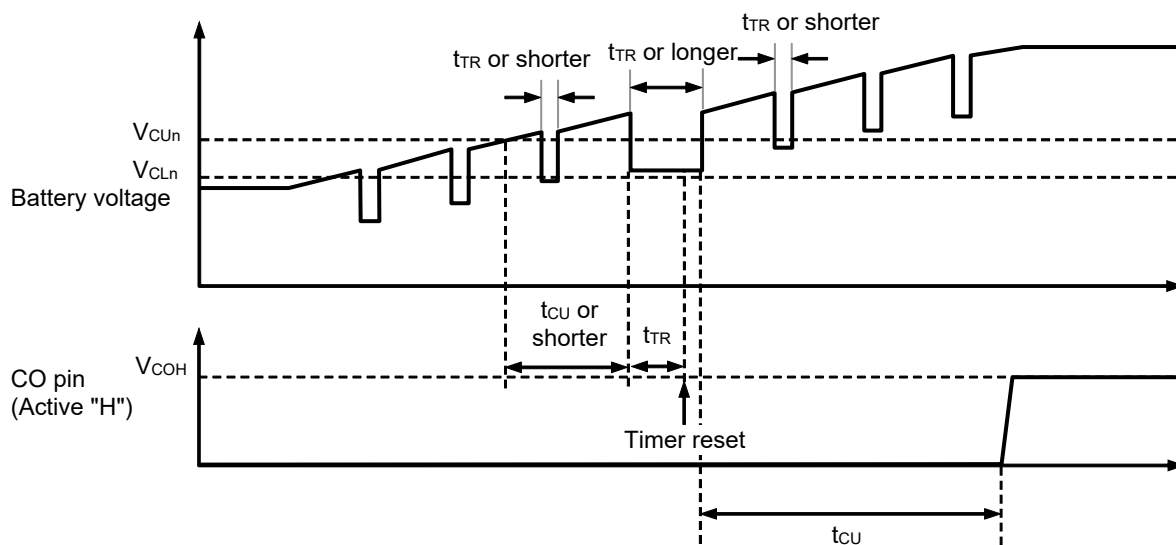
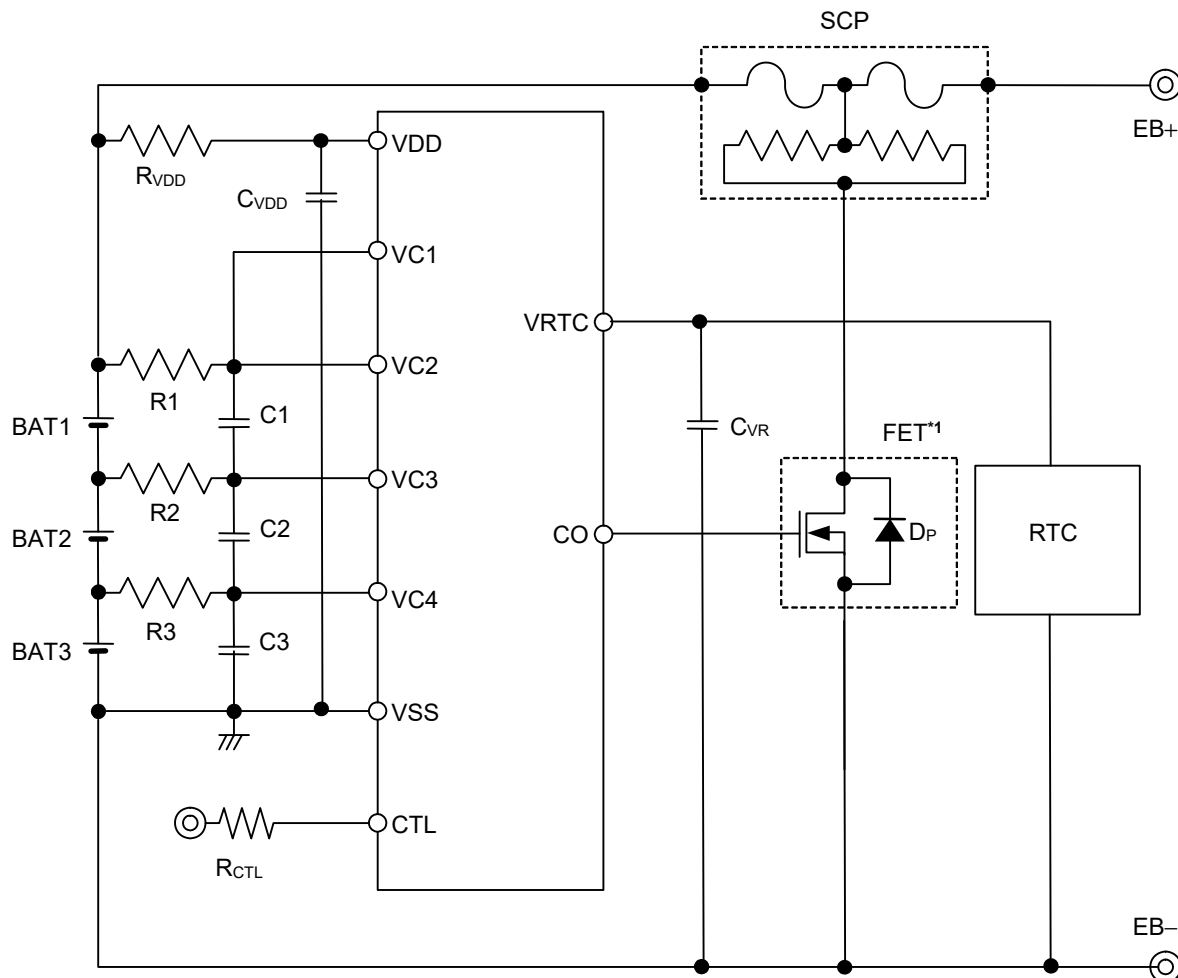


Figure 10

Remark n = 1, 2, 3, 4

■ **Battery Protection IC Connection Examples**

1. **S-82M3A Series (3-serial cell)**



\*1. This IC limits its CO pin output voltage to 7.5 V max., so a FET with the gate withstand voltage of 8 V can be used.

Figure 11

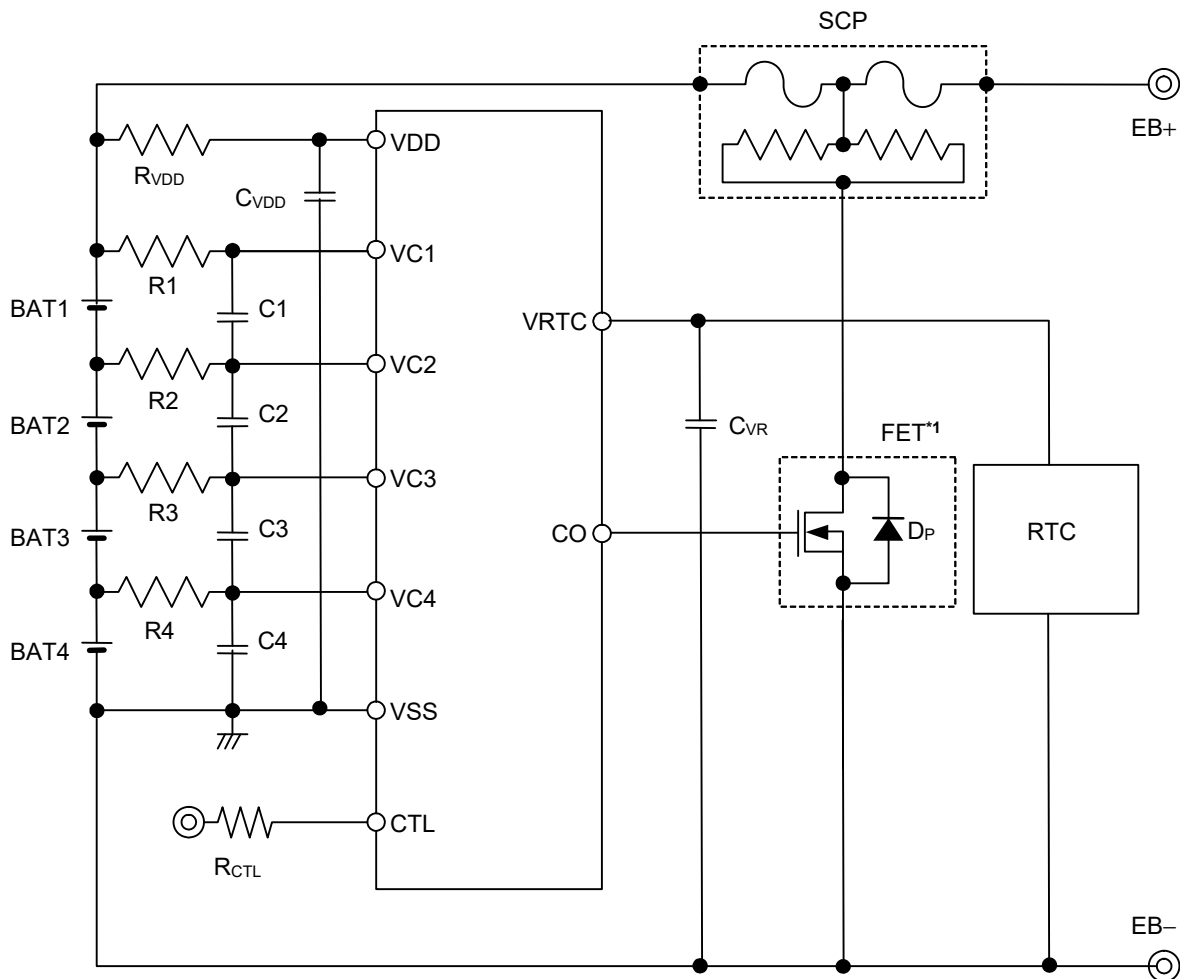
Table 10 Constants for External Components

No.	Part	Min.	Typ.*1	Max.	Unit
1	R1 to R3	1	1	1	kΩ
2	C1 to C3, CVDD	0.1	0.1	1	μF
3	RVDD	100	100	1000	Ω
4	CVR	—	0.1	—	μF
5	RCTL	—	1.0	—	kΩ

\*1. Accuracy of overcharge detection voltage is guaranteed by typ. value in Table 10. Connecting components with other values will worsen the accuracy.

- Caution**
1. The constants may be changed without notice.
  2. It has not been confirmed whether the operation is normal or not in circuits other than the connection examples. In addition, the connection examples and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
  3. Set the same constants to R1 to R3 and to C1 to C3 and CVDD.

2. S-82M4A Series (4-serial cell)



\*1. This IC limits its CO pin output voltage to 7.5 V max., so a FET with the gate withstand voltage of 8 V can be used.

Figure 12

Table 11 Constants for External Components

No.	Part	Min.	Typ.*1	Max.	Unit
1	R1 to R4	1	1	1	kΩ
2	C1 to C4, C_VDD	0.1	0.1	1	μF
3	R_VDD	100	100	1000	Ω
4	C_VR	–	0.1	–	μF
5	R_CTL	–	1.0	–	kΩ

\*1. Accuracy of overcharge detection voltage is guaranteed by typ. value in Table 11. Connecting components with other values will worsen the accuracy.

- Caution**
1. The constants may be changed without notice.
  2. It has not been confirmed whether the operation is normal or not in circuits other than the connection examples. In addition, the connection examples and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
  3. Set the same constants to R1 to R4 and to C1 to C4 and C\_VDD.

**[For SCP, contact]**

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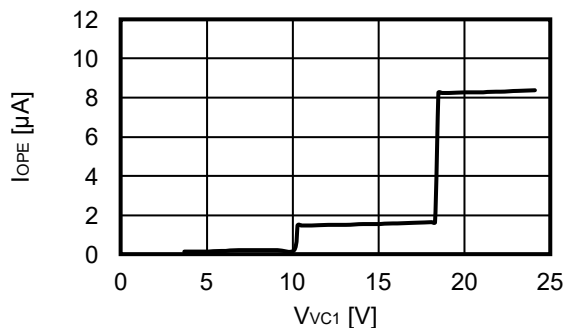
## ■ Precaution

- Before the battery connection, short-circuit the battery side pins  $R_{VDD}$  and R1, shown in the figures in "■ **Battery Protection IC Connection Examples**".
- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply to this IC an electrostatic discharge that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement of patents owned by a third party by products including this IC.

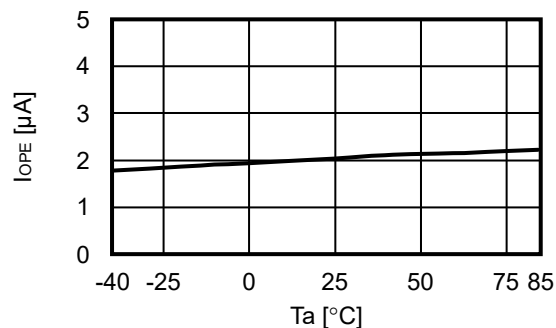
## ■ Characteristics (Typical Data)

### 1. Current consumption

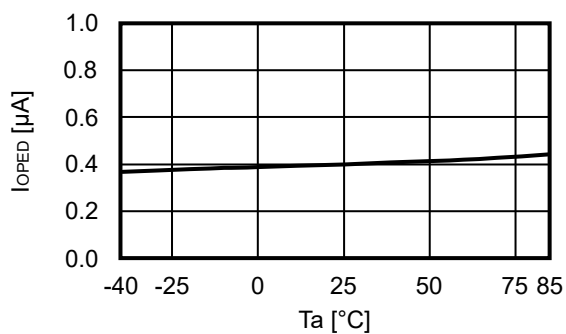
1. 1  $I_{OPE}$  vs.  $V_{VC1}$



1. 2  $I_{OPE}$  vs.  $T_a$

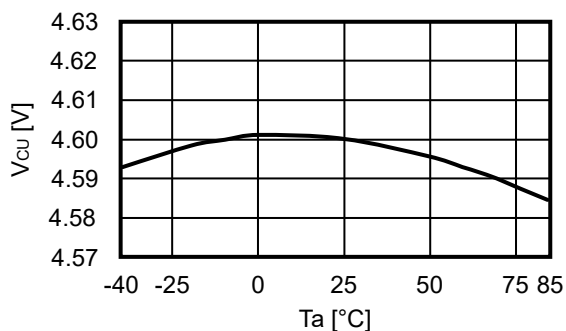


1. 3  $I_{OPED}$  vs.  $T_a$

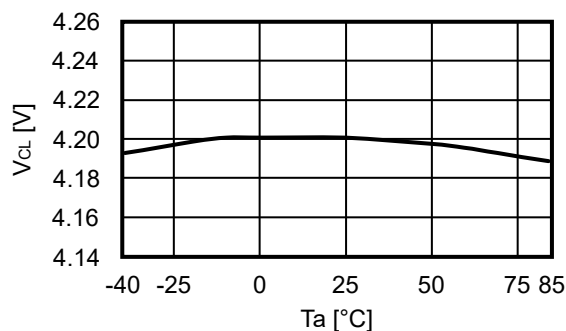


### 2. Detection voltage, release voltage

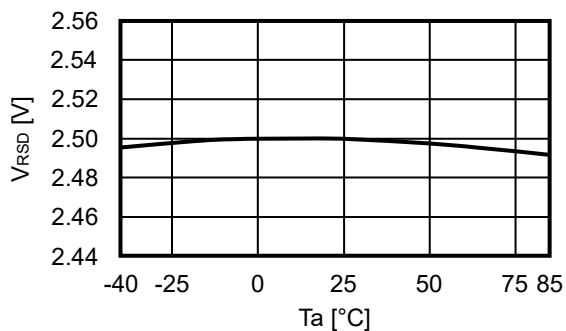
2. 1  $V_{CU}$  vs.  $T_a$



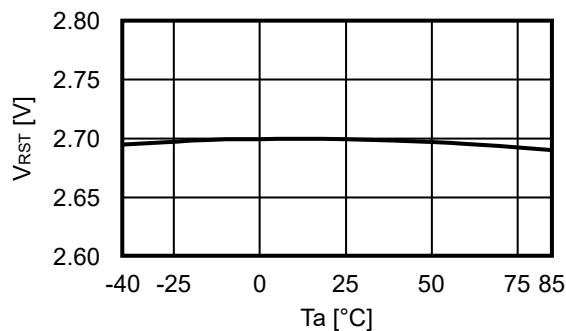
2. 2  $V_{CL}$  vs.  $T_a$



2. 3  $V_{RSD}$  vs.  $T_a$

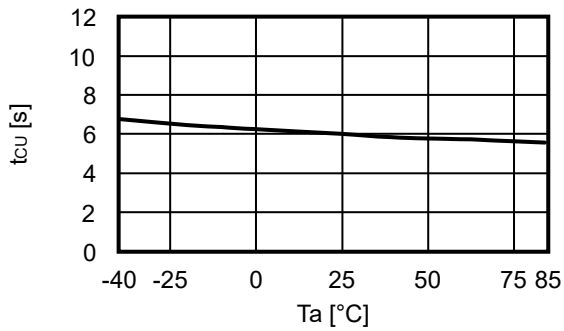


2. 4  $V_{RST}$  vs.  $T_a$

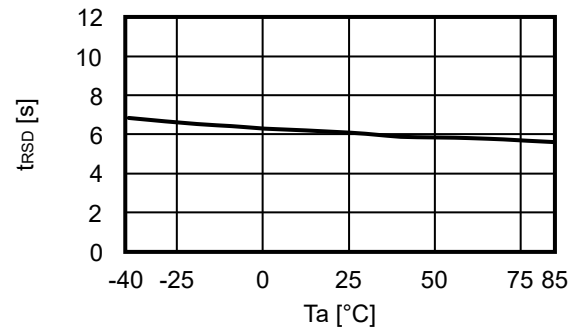


**3. Delay time**

**3.1  $t_{CU}$  vs.  $T_a$**

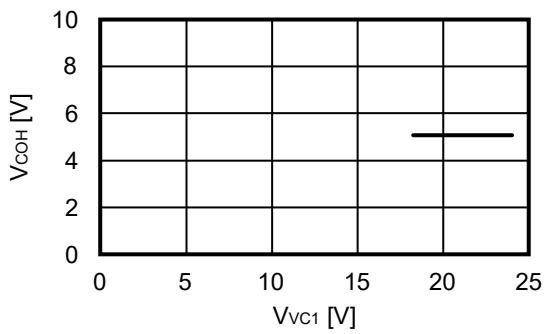


**3.2  $t_{RSD}$  vs.  $T_a$**

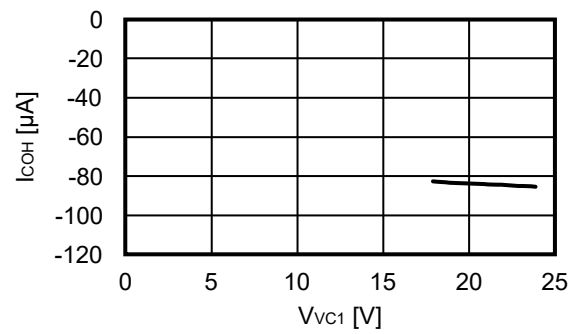


**4. Output pin**

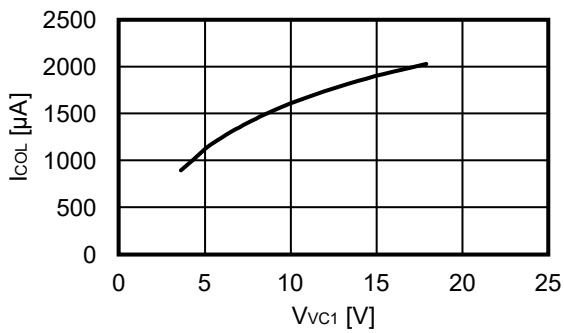
**4.1  $V_{COH}$  vs.  $V_{VC1}$**



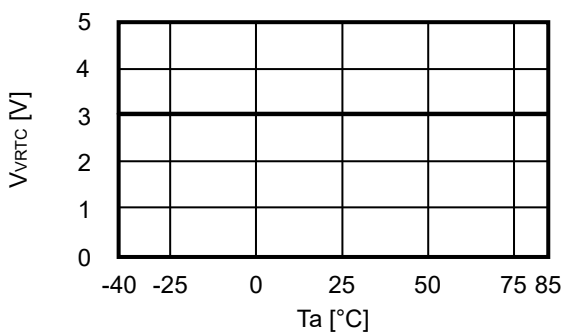
**4.2  $I_{COH}$  vs.  $V_{VC1}$**



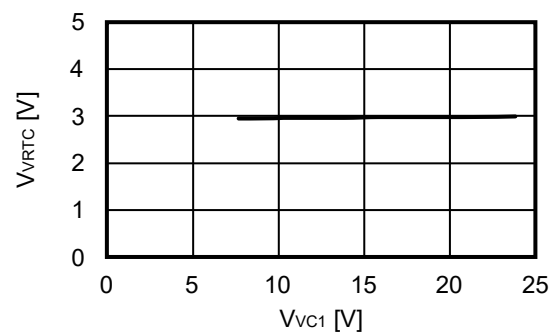
**4.3  $I_{COL}$  vs.  $V_{VC1}$**



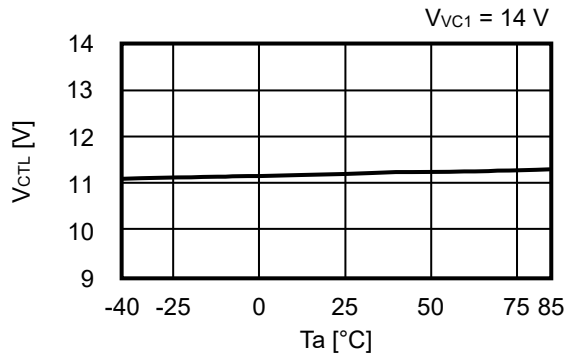
**4.4  $V_{VRTC}$  vs.  $T_a$**



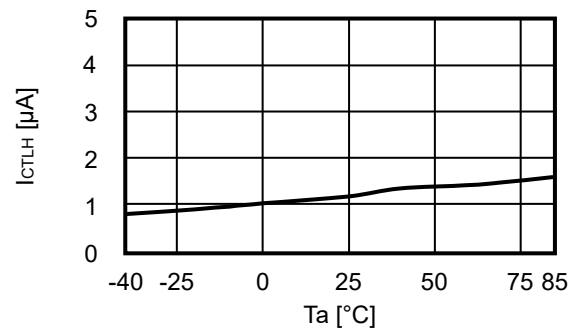
**4.5  $V_{VRTC}$  vs.  $V_{VC1}$**



**4.6  $V_{CTL}$  vs.  $T_a$**

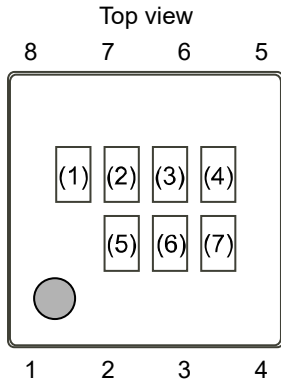


**4.7  $I_{CTLH}$  vs.  $T_a$**



■ **Marking Specifications**

**1. DFN-8(2020)A**



- (1): Blank
- (2) to (4): Product code (Refer to **Product name vs. Product code**)
- (5) to (7): Lot number

**Product name vs. Product code**

**1.1 S-82M3A Series**

Product name	Product code		
	(2)	(3)	(4)
S-82M3AAA-A8T8U	9	Z	A

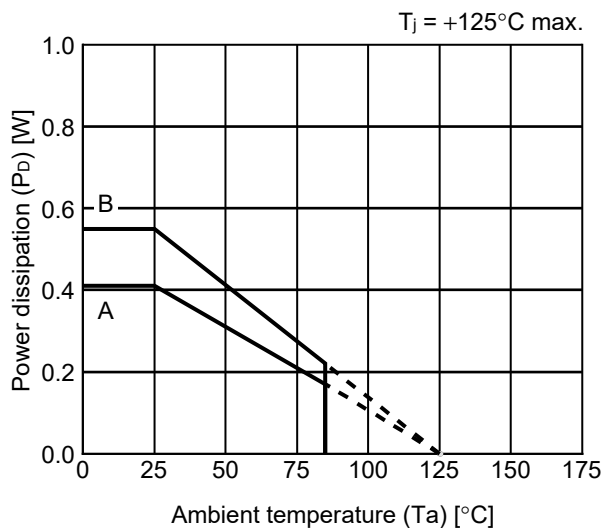
**1.2 S-82M4A Series**

Product name	Product code		
	(2)	(3)	(4)
S-82M4AAA-A8T8U	9	Z	R




■ **Power Dissipation**

**DFN-8(2020)A**

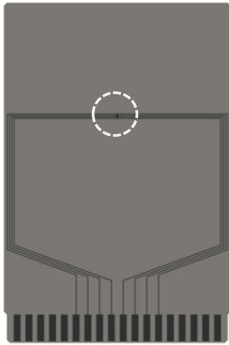


Board	Power Dissipation ( $P_D$ )
A	0.41 W
B	0.55 W
C	—
D	—
E	—

# DFN-8(2020)A Test Board

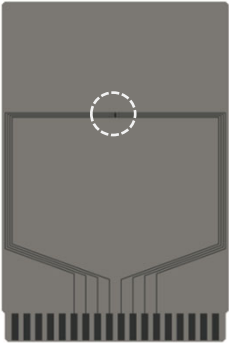
 IC Mount Area

(1) Board A



Item	Specification	
Size [mm]	114.3 x 76.2 x t1.6	
Material	FR-4	
Number of copper foil layer	2	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via	-	

(2) Board B

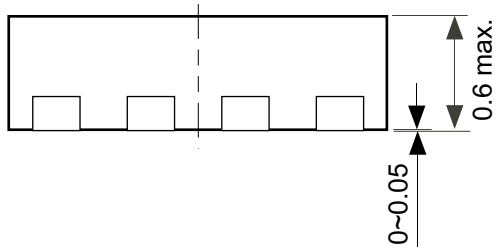
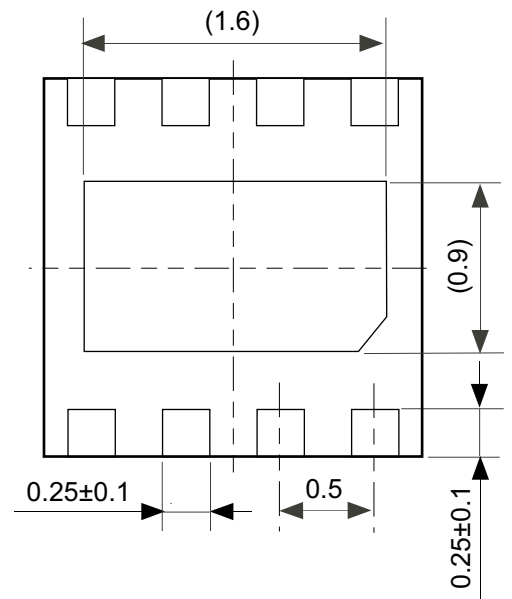
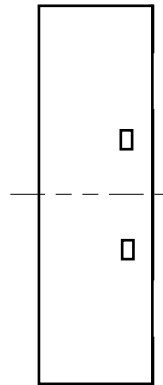
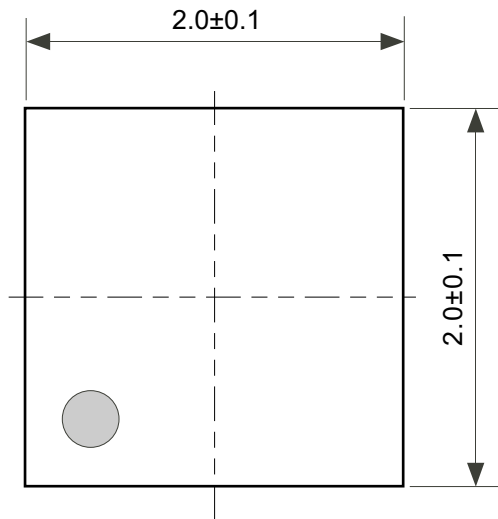


Item	Specification	
Size [mm]	114.3 x 76.2 x t1.6	
Material	FR-4	
Number of copper foil layer	4	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via	-	



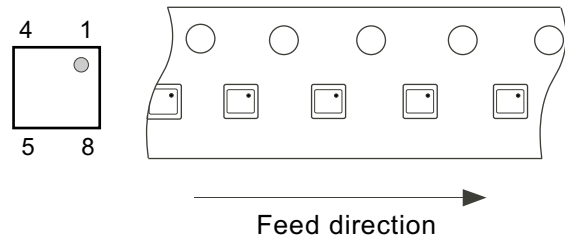
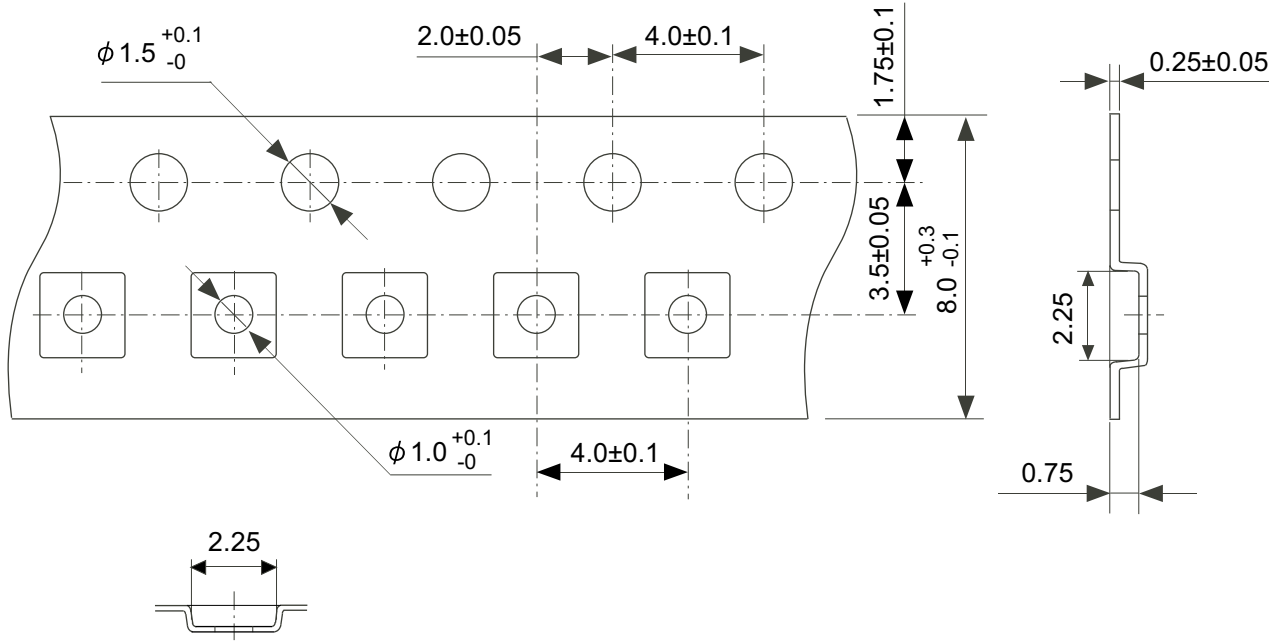
enlarged view

No. DFN8-E-Board-SD-1.0



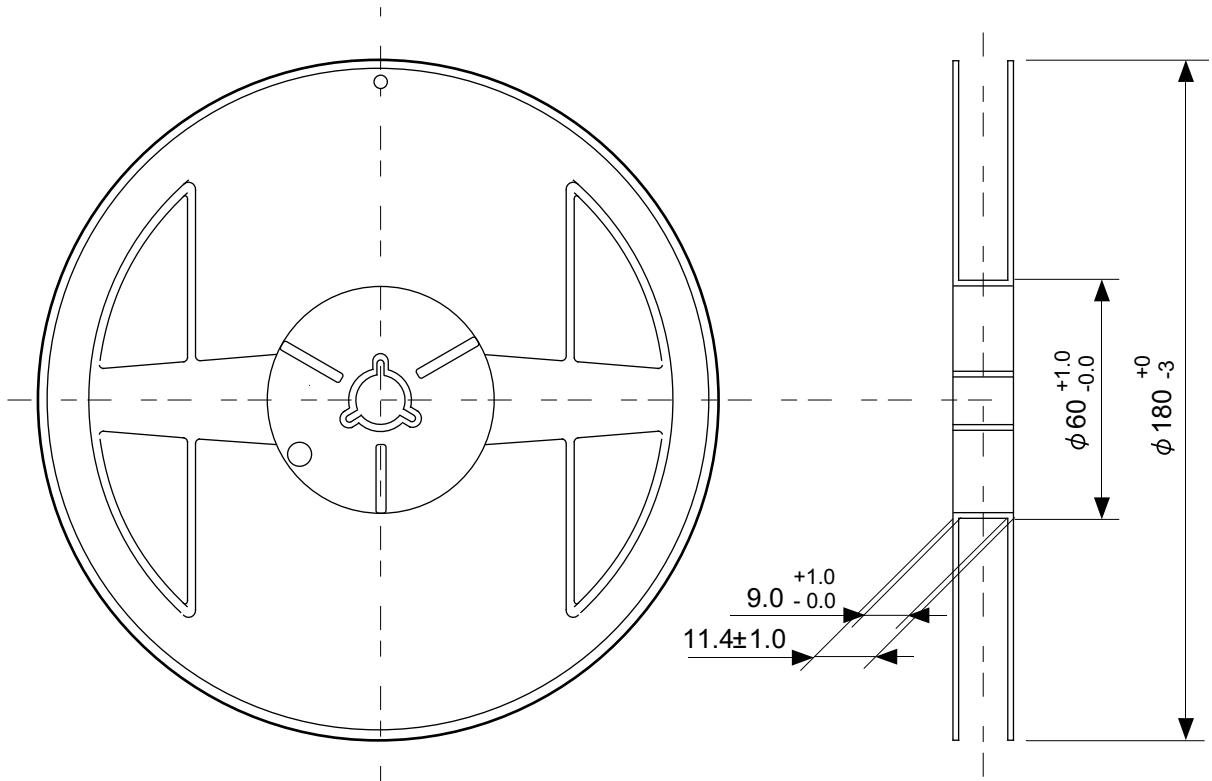
No. IB008-A-P-SD-2.0

TITLE	DFN-8-E-PKG Dimensions
No.	IB008-A-P-SD-2.0
ANGLE	
UNIT	mm
<b>ABLIC Inc.</b>	

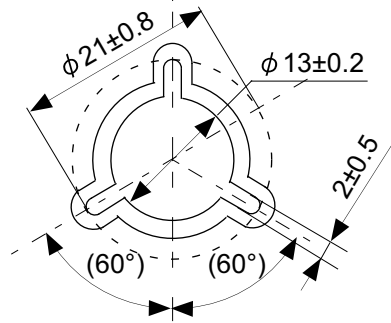


No. IB008-A-C-SD-1.0

TITLE	DFN-8-E-Carrier Tape
No.	IB008-A-C-SD-1.0
ANGLE	
UNIT	mm
<b>ABLIC Inc.</b>	



Enlarged drawing in the central part



No. IB008-A-R-SD-1.0

TITLE	DFN-8-E-Reel		
No.	IB008-A-R-SD-1.0		
ANGLE		QTY.	4,000
UNIT	mm		
<b>ABLIC Inc.</b>			



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2.4-2019.07